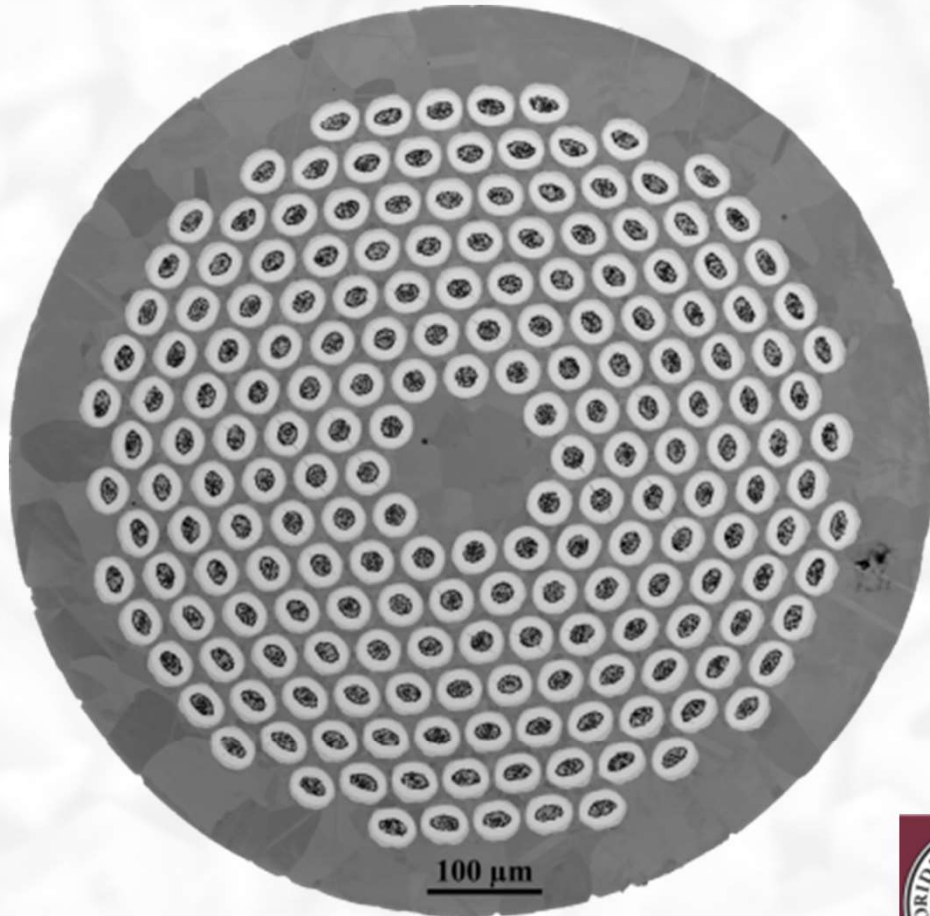


# Root cause of large grain A15 formation in Powder In Tube $Nb_3Sn$ conductors



**Chris Segal**

September 5th, 2016



APPLIED  
SUPERCONDUCTIVITY  
CENTER



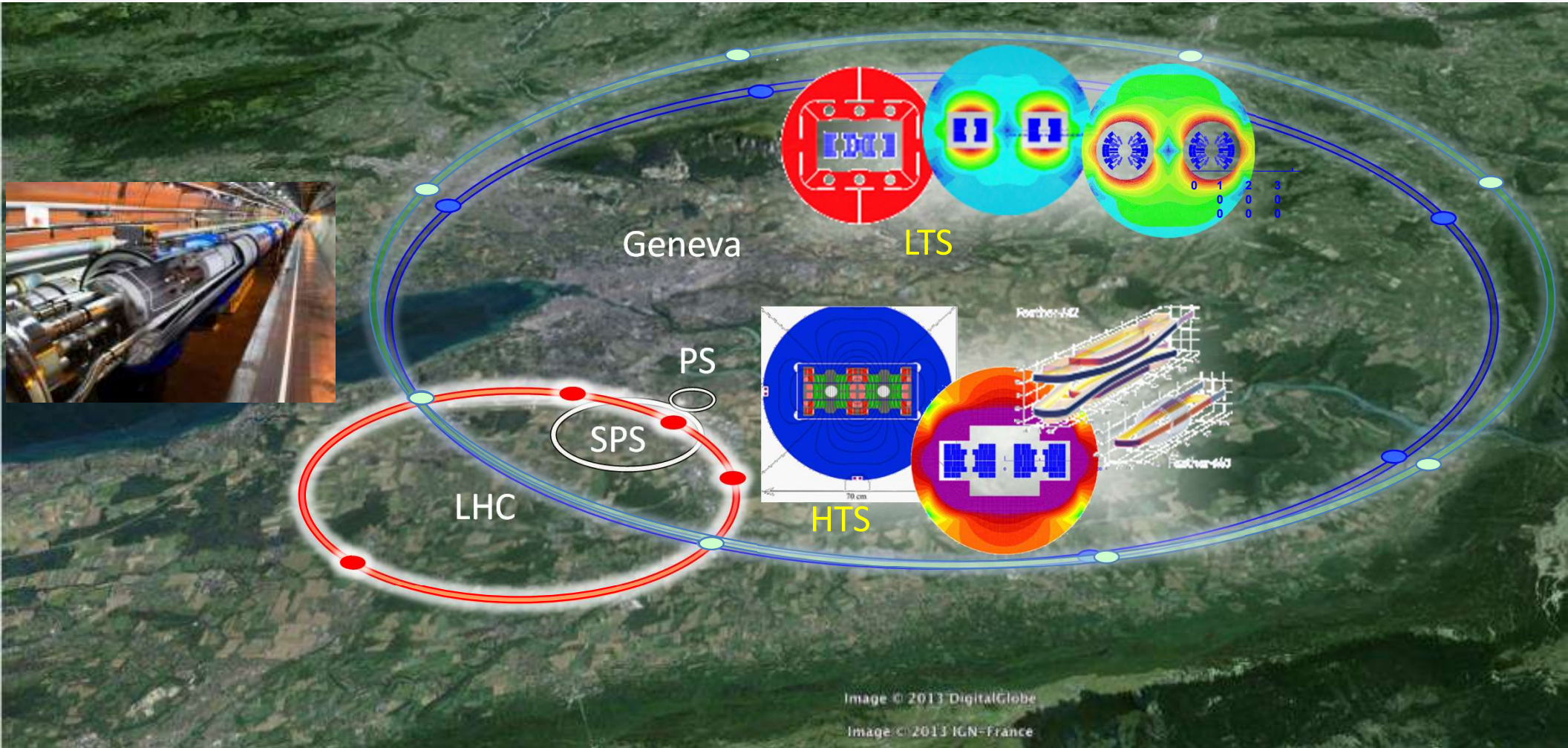
NATIONAL HIGH

**MAGNETIC**

**FIELD LABORATORY**



# The FCC playground



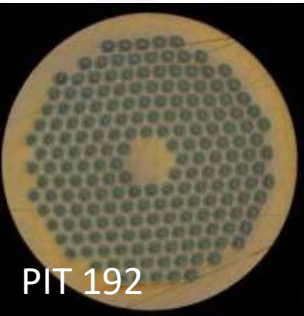
**LHC**  
 27 km, 8.33 T  
 14 TeV (c.o.m.)  
 1300 tons NbTi

**HE-LHC**  
 27 km, **20 T**  
 33 TeV (c.o.m.)  
 3000 tons LTS  
 700 tons HTS

**FCC-hh**  
 80 km, **20 T**  
 100 TeV (c.o.m.)  
 9000 tons LTS  
 2000 tons HTS

**FCC-hh**  
 100 km, **16 T**  
 100 TeV (c.o.m.)  
 6000 tons Nb<sub>3</sub>Sn  
 3000 tons Nb-Ti

# The practical HiLumi Nb<sub>3</sub>Sn wire is in production!

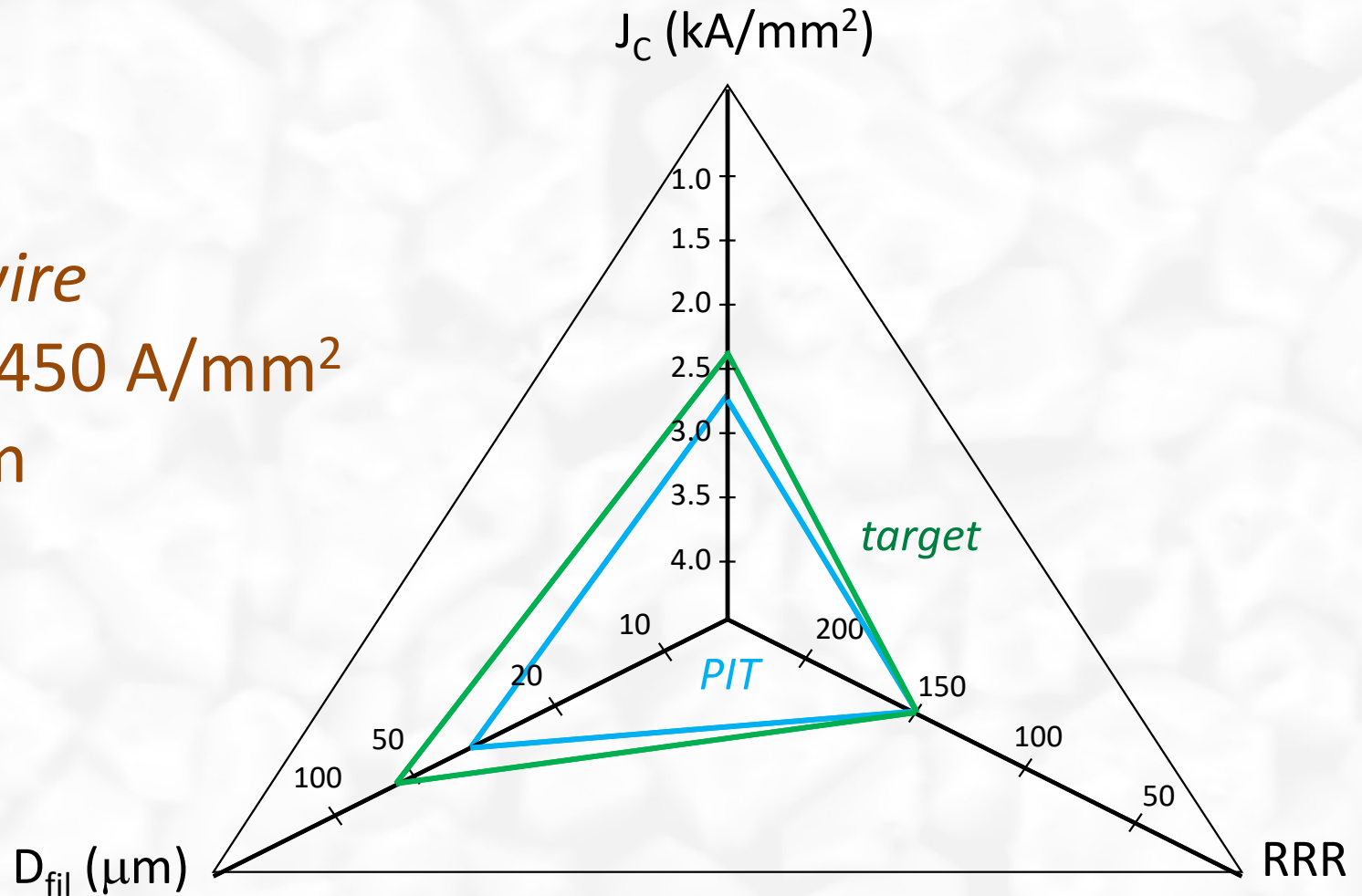


*Practical wire*

$J_C(12T) > 2450 \text{ A/mm}^2$

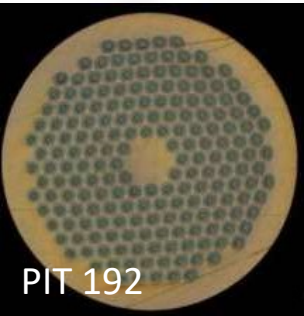
$D_{\text{fil}} < 55 \mu\text{m}$

$\text{RRR} > 150$





# Looking to the future FCC wire

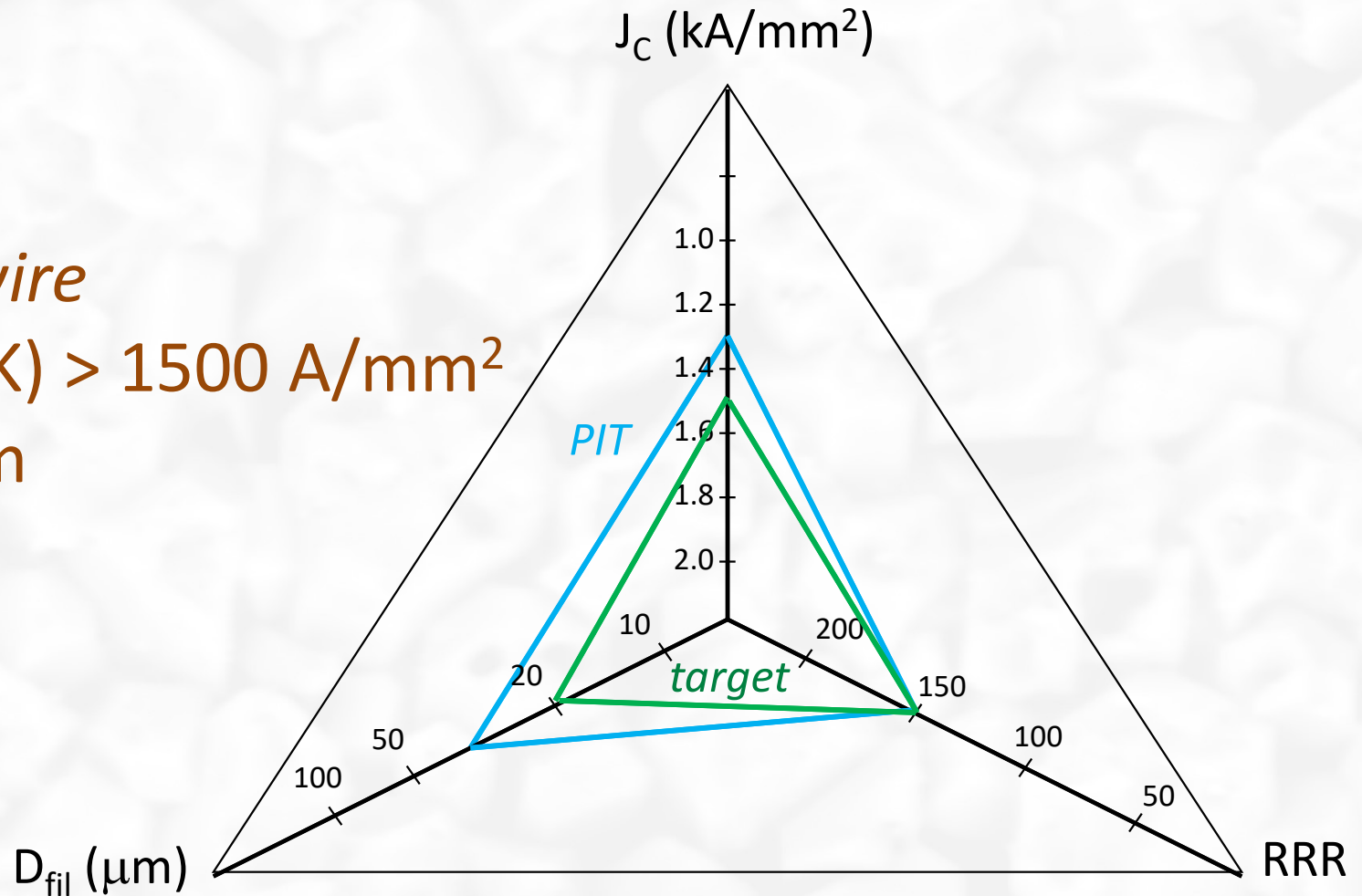


*Practical wire*

$J_C(16T, 4.2K) > 1500 \text{ A/mm}^2$

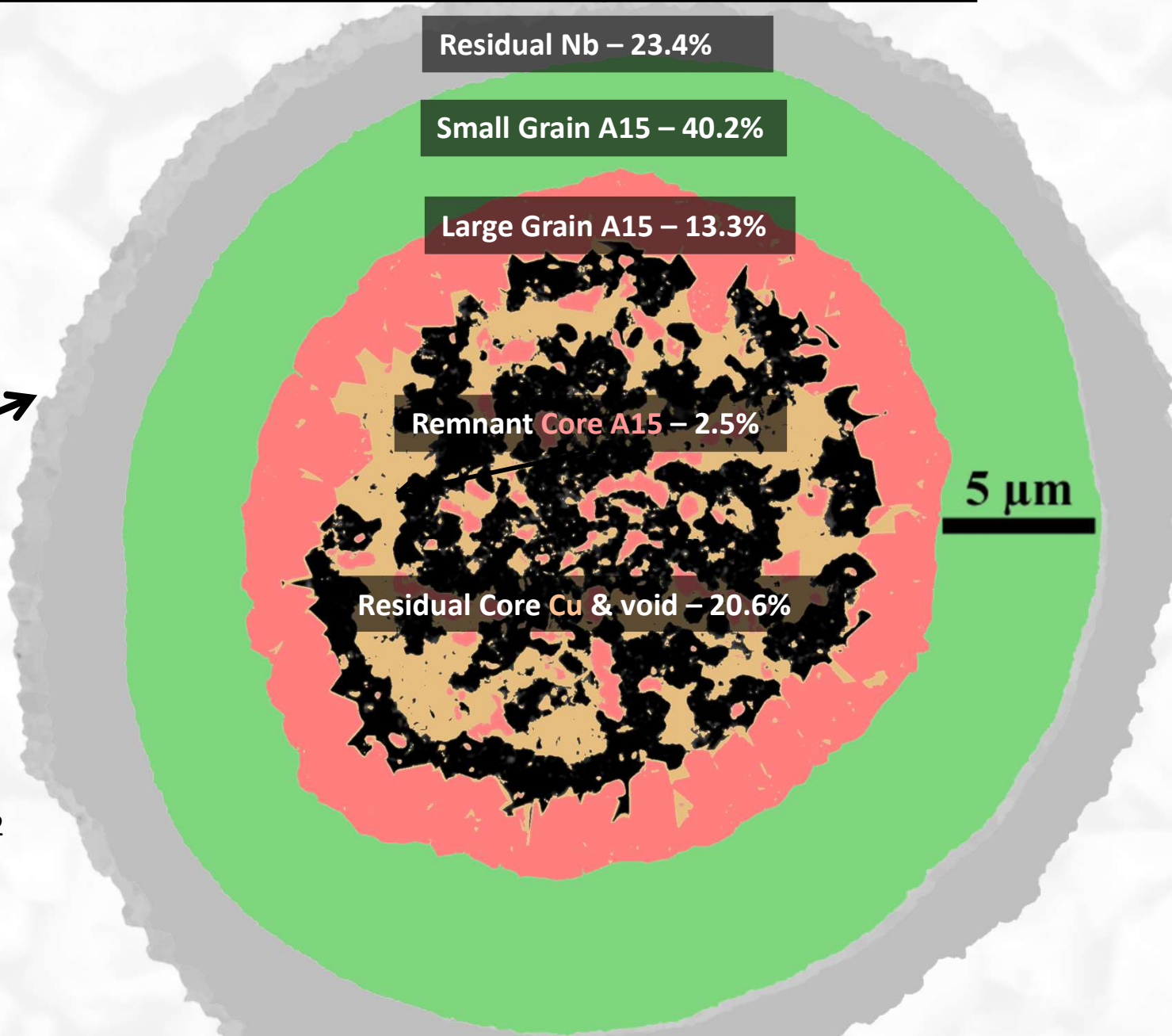
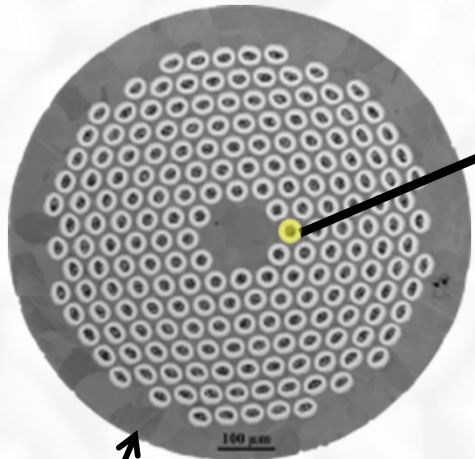
$D_{\text{fil}} < 20 \mu\text{m}$

$RRR > 150$



# The Fractional Real Estate of PIT – only 40% is valuable

- Wire diameter: 0.78mm
- Filament diameter: 39  $\mu\text{m}$
- HT from BEAS:
- 620/100 + 640/120



- $I_c = 501 \text{ A}$
- $J_{c \text{ non-Cu}} = 2237 \text{ A/mm}^2$
- $J_{c \text{ -layer}} = 5564 \text{ A/mm}^2$

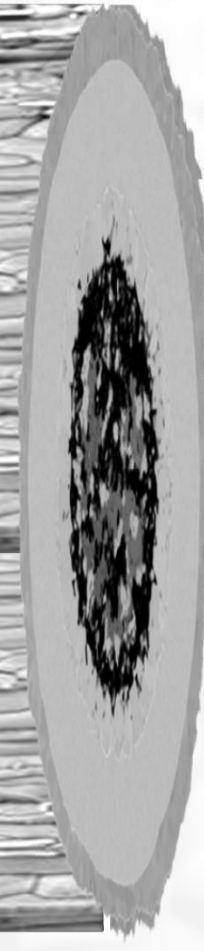
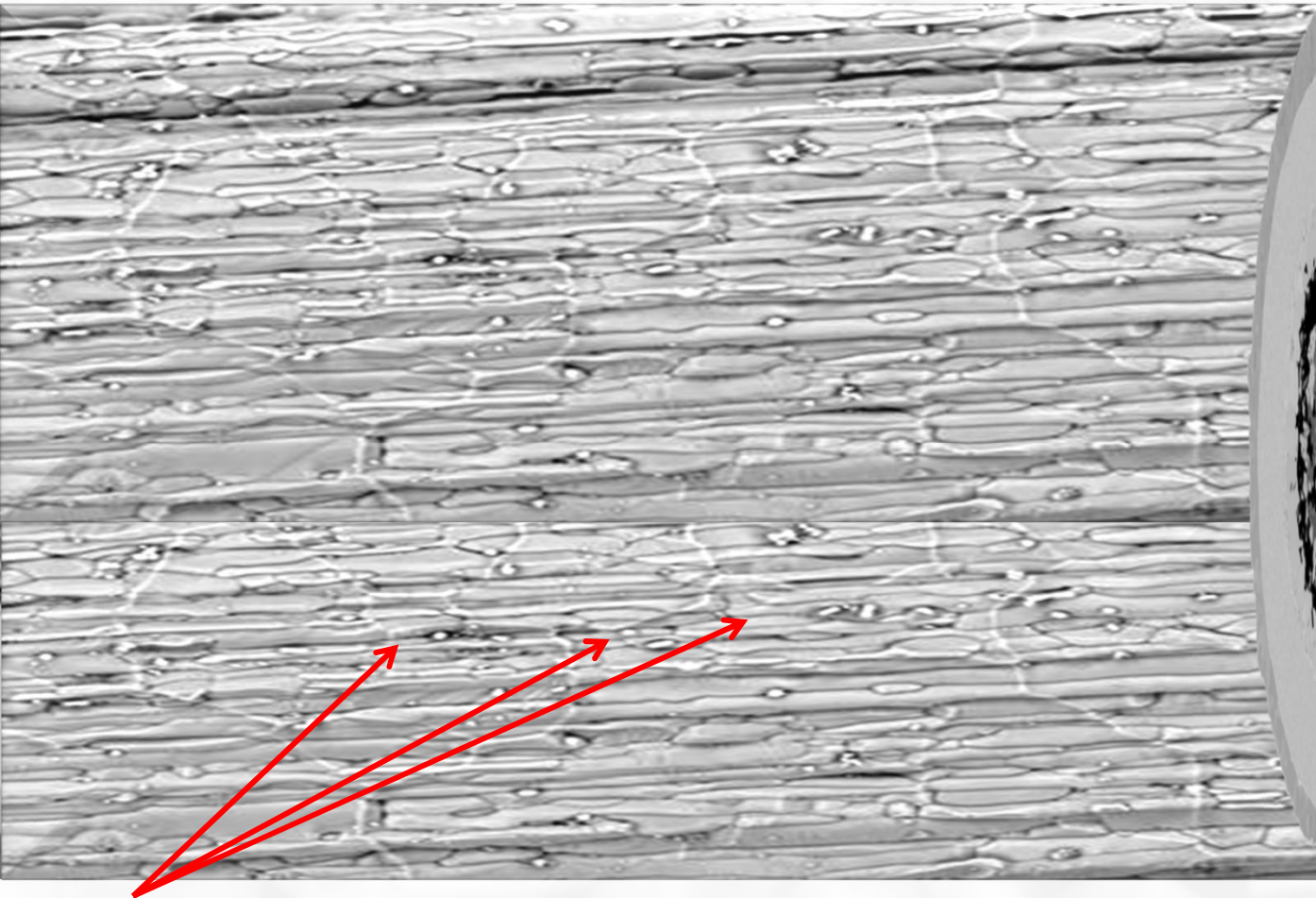
- Only **small grain A15** carries current
- **Large and core grains of A15** do not carry any current (seen on next slide)

# Can **large grains** really carry current?

Why does the **LG** form?

Can we manage it's formation?

Here we look at the phase evolution



**LG A15**  
appears very  
disconnected

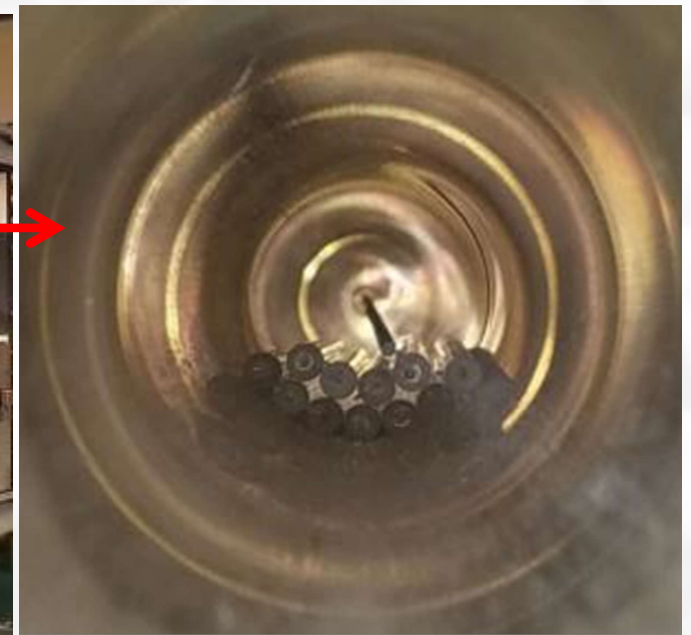
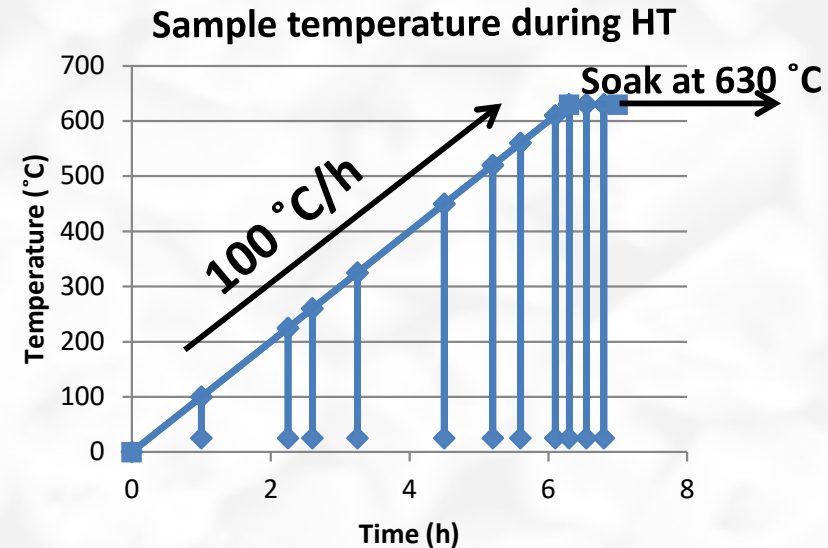
**Cu-rich** phases penetrate between LG's

630C200h Billet B29992  
Longitudinal Cross Section



# Furnace set up for sample quenching

- Samples are pulled out of the furnace and quenched in cold water, indicated by vertical lines in the plot to the right.
- This rapid cooling 'freezes' the microstructure at the reaction temperature, allowing examination of phases and chemical compositions which are present.

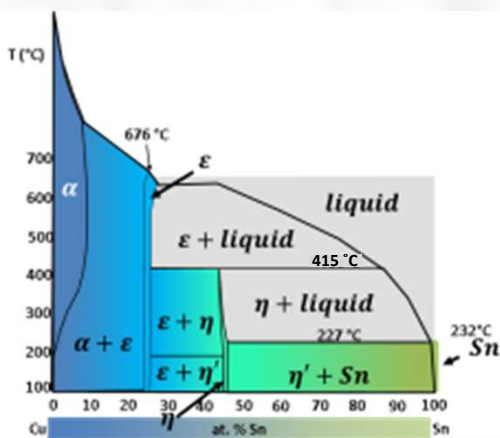
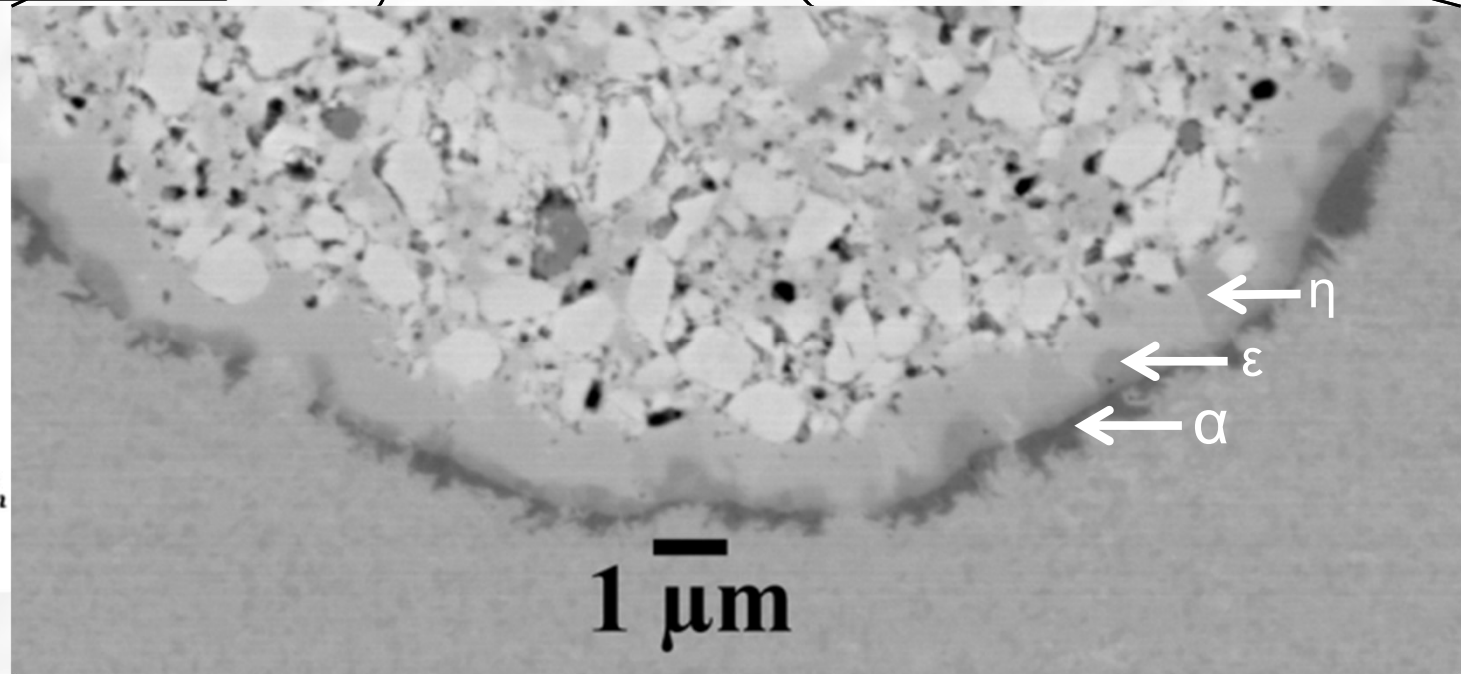
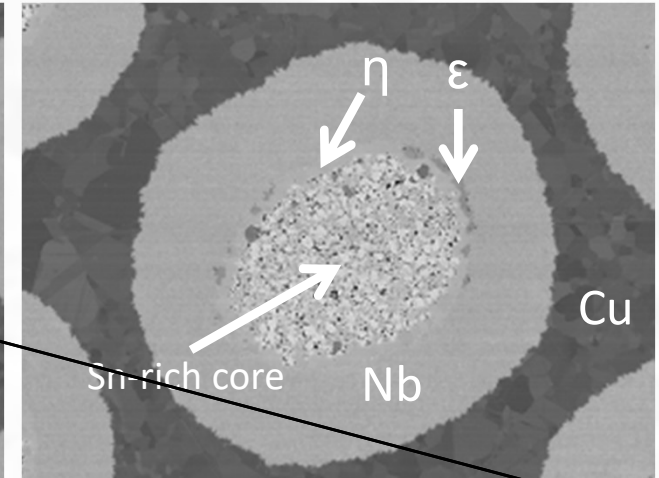
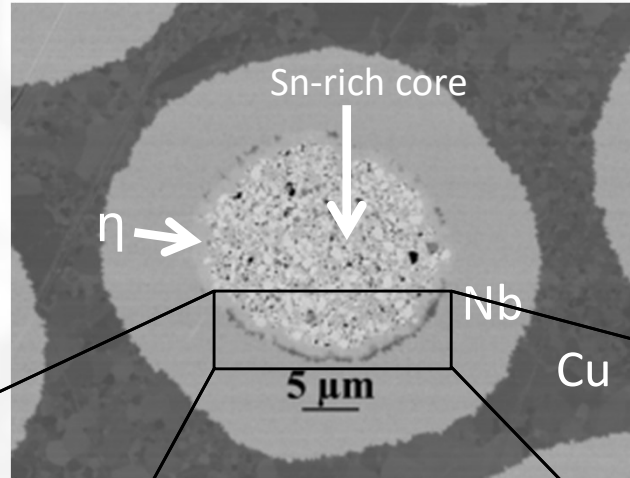


# Sn is rapidly absorbed by Cu sleeve to form $\eta$ early in the reaction

Original Nb tube is inscribed by a Cu sleeve, and the core filled with a Sn rich powder

225 °C

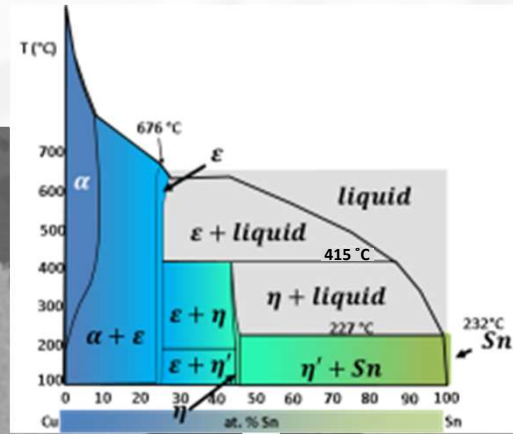
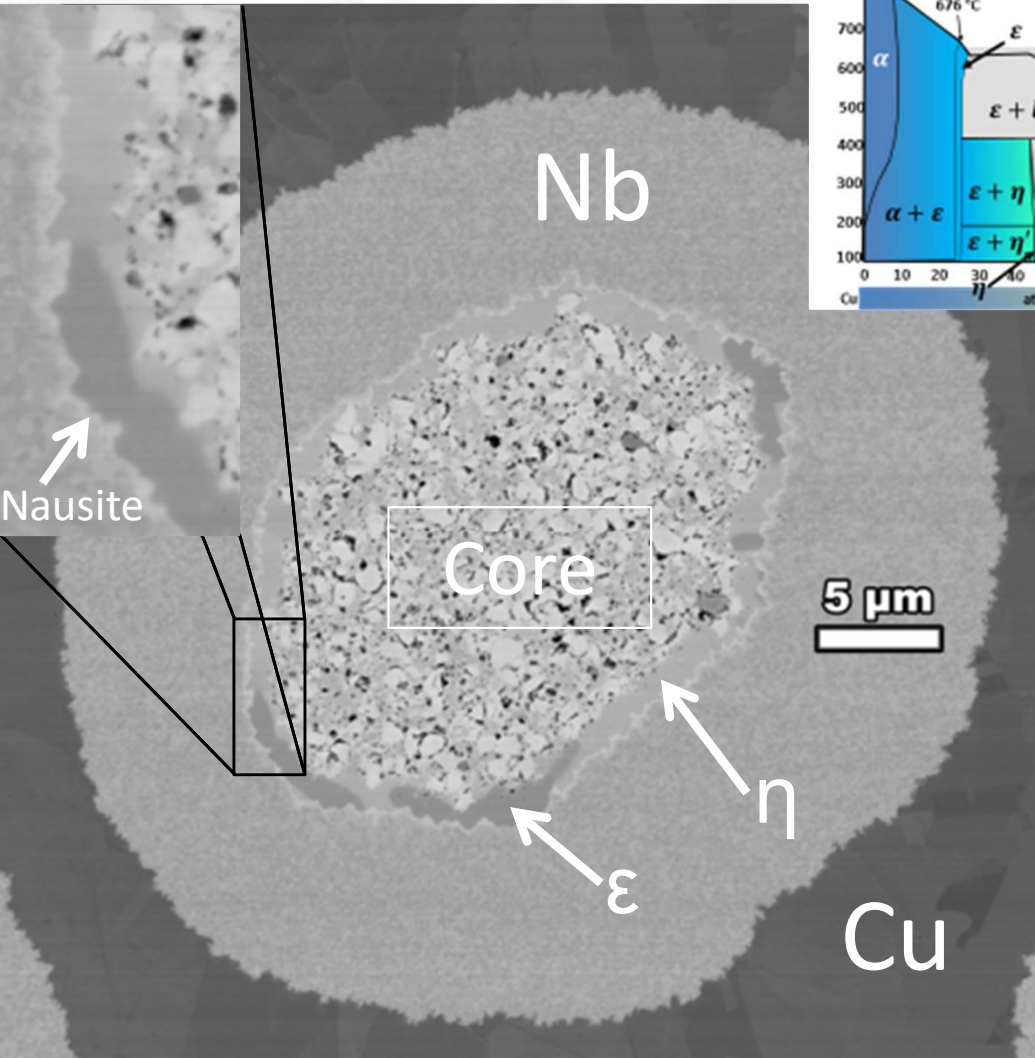
260 °C



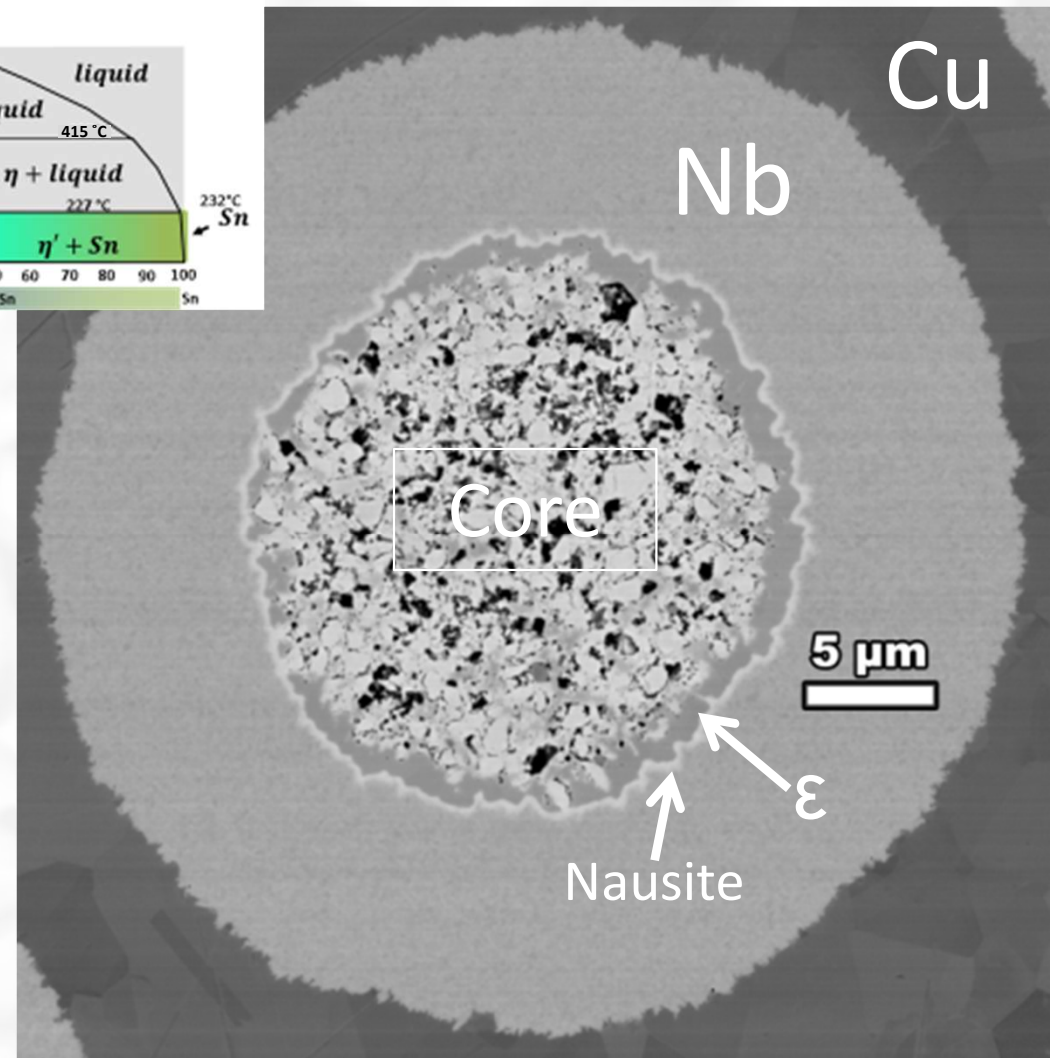


# $\eta$ transforms to $\epsilon$ at 408°C, Nausite grows as a continuous layer

400°C



450°C



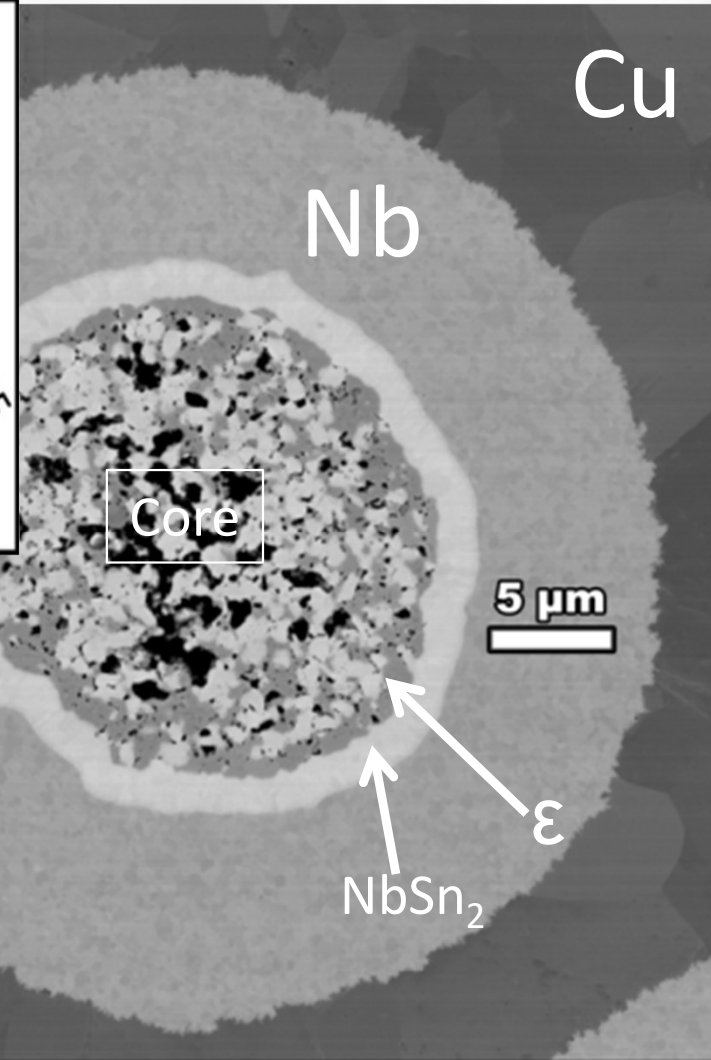
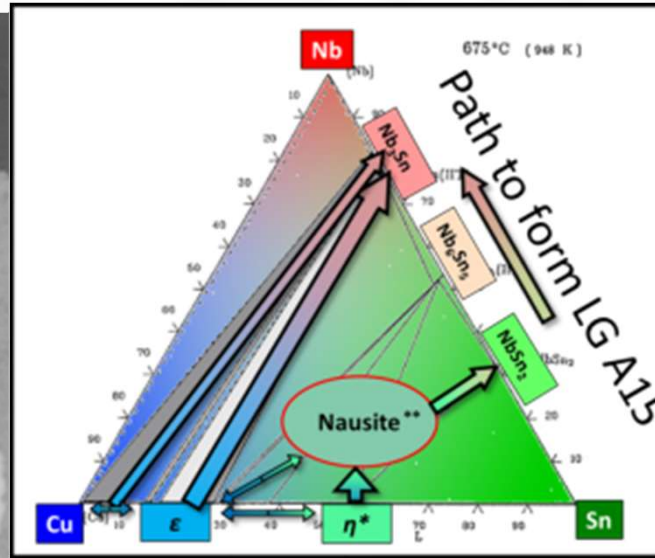
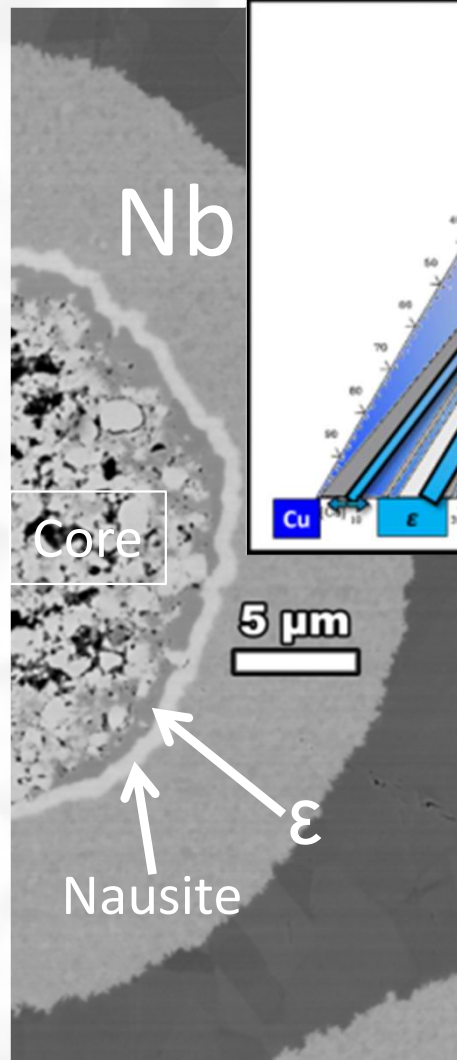
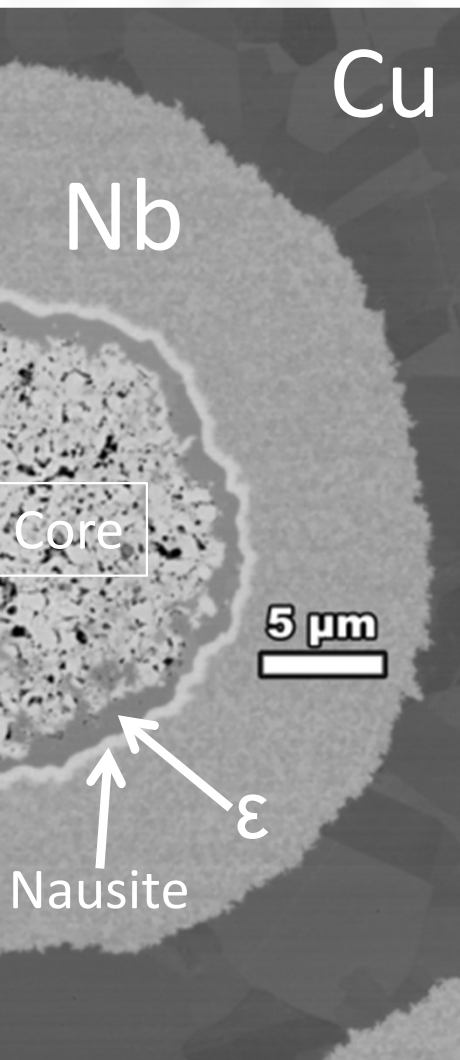
- Thin, continuous ring of Nausite between Nb and the layer of  $\eta/\epsilon$  phase.
- Since  $\eta$  decomposes at 415°C,  $\epsilon$  begins forming

- $\eta$  has entirely transformed into  $\epsilon$  phase
- Nausite ring rows

Nausite decomposes above 560 °C and by 610 °C the Sn rich layer is entirely NbSn<sub>2</sub>

520 °C → 560 °C

610 °C



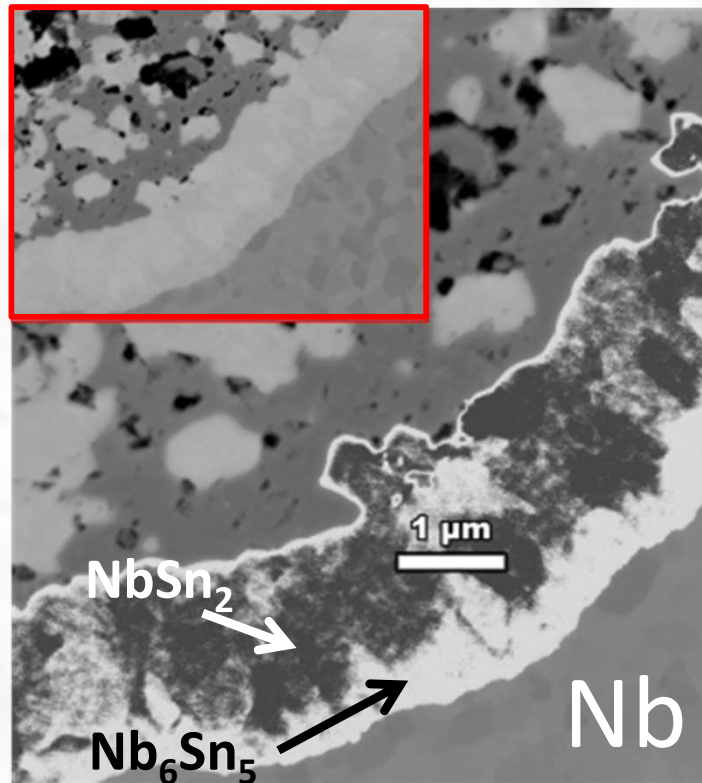
- Nausite ring grows

- Full layer of NbSn<sub>2</sub> forms from Nausite expelling Cu

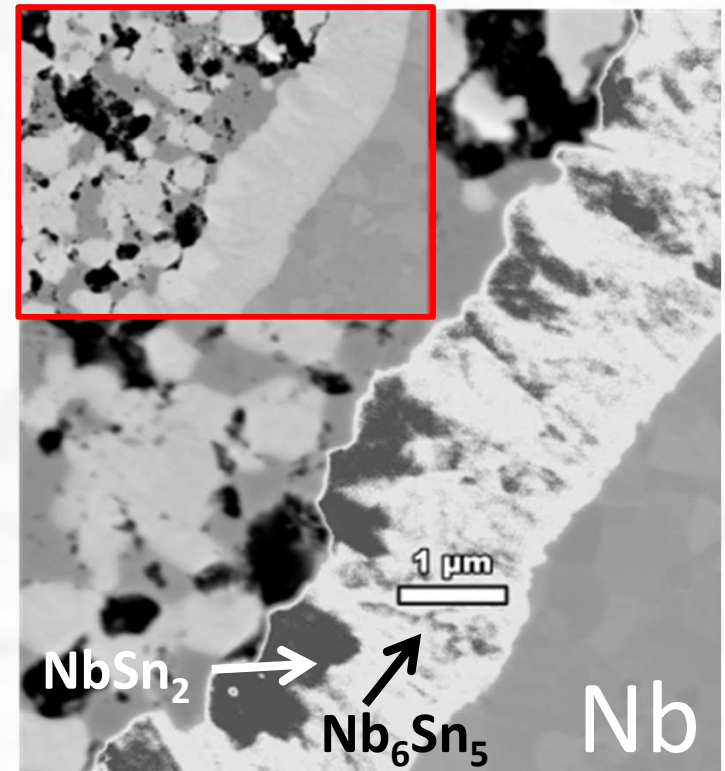


# At 630°C NbSn<sub>2</sub> rapidly transforms into Nb<sub>6</sub>Sn<sub>5</sub>

**0 minutes**



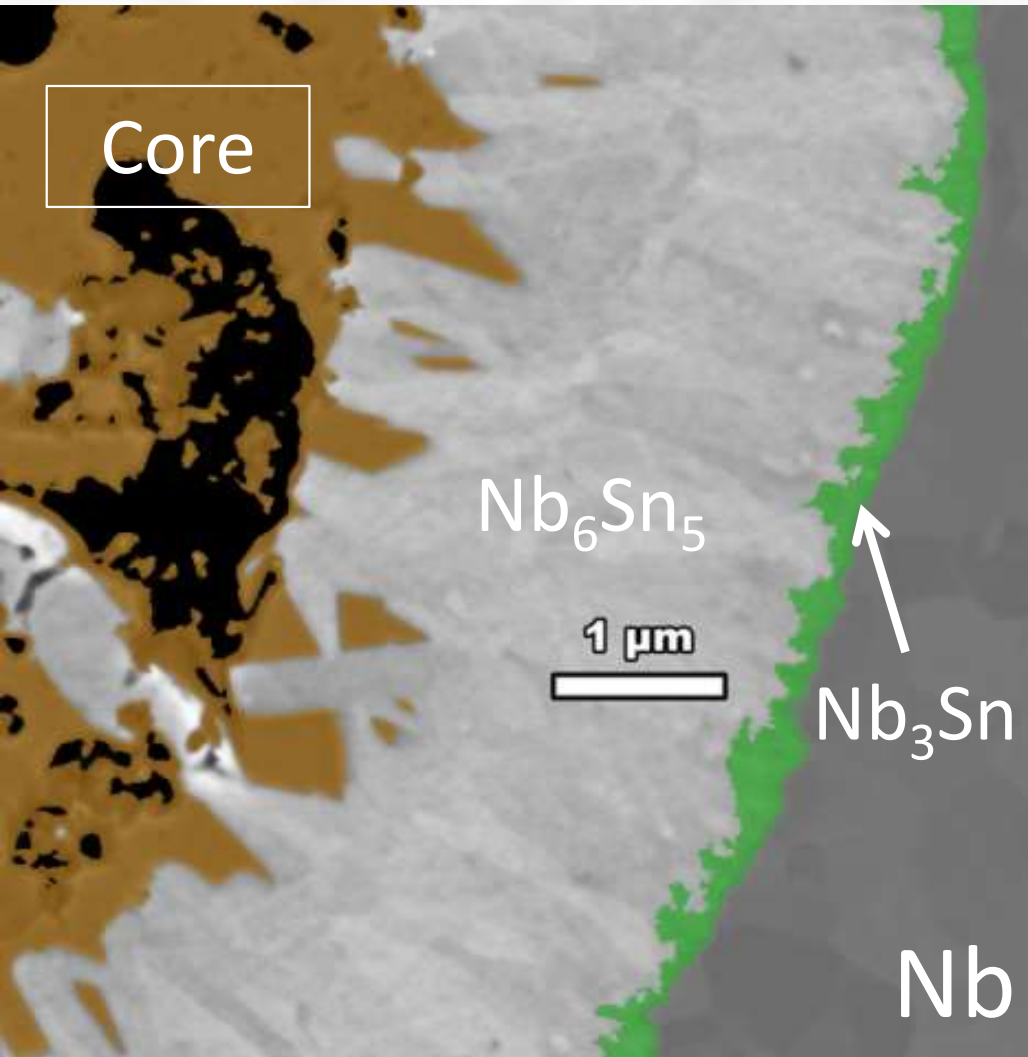
**30 minutes**



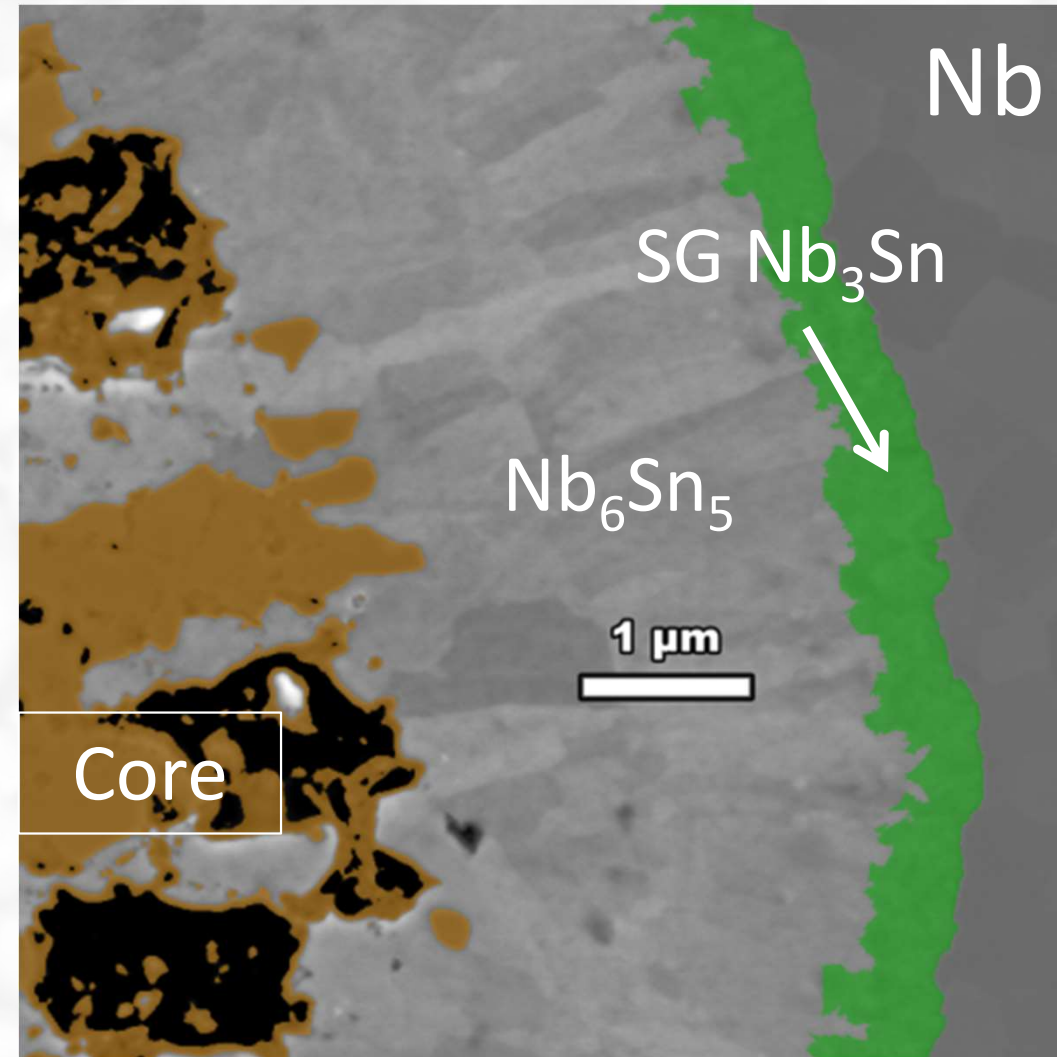
- The transformation occurs quickly; about 45 minutes at 630°C
- The Nb<sub>6</sub>Sn<sub>5</sub> contains a few at% Cu

# Continuous layer of small grain $\text{Nb}_3\text{Sn}$ is formed by 5 hours

**630°C - 5hr**



**630°C - 10hr**



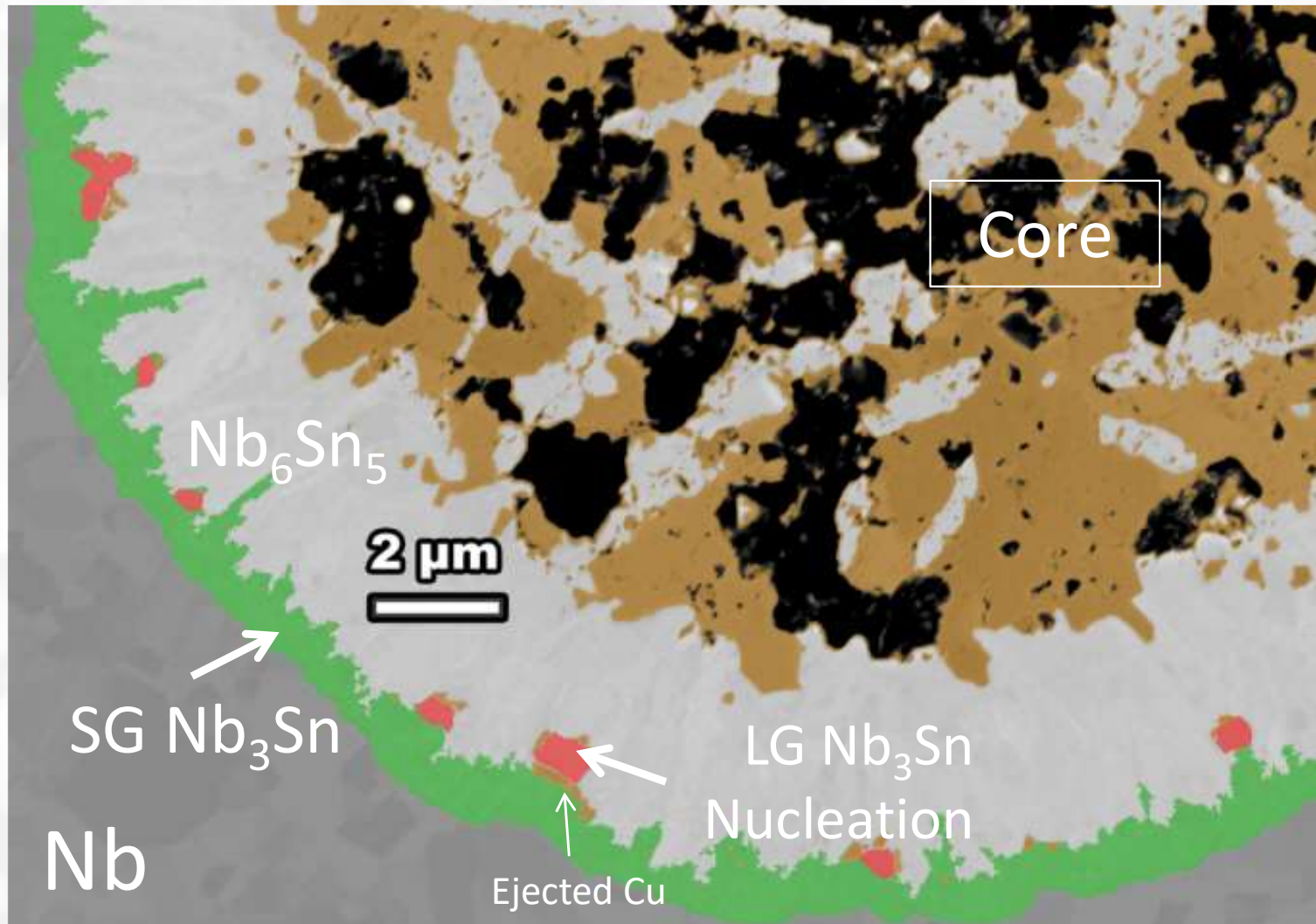
- $\text{Nb}_6\text{Sn}_5$  draws Sn from core to Nb barrier

- $\text{Nb}_3\text{Sn}$  layer has grown



# LG A15 has formed with the ejection of Cu by $\text{Nb}_6\text{Sn}_5$

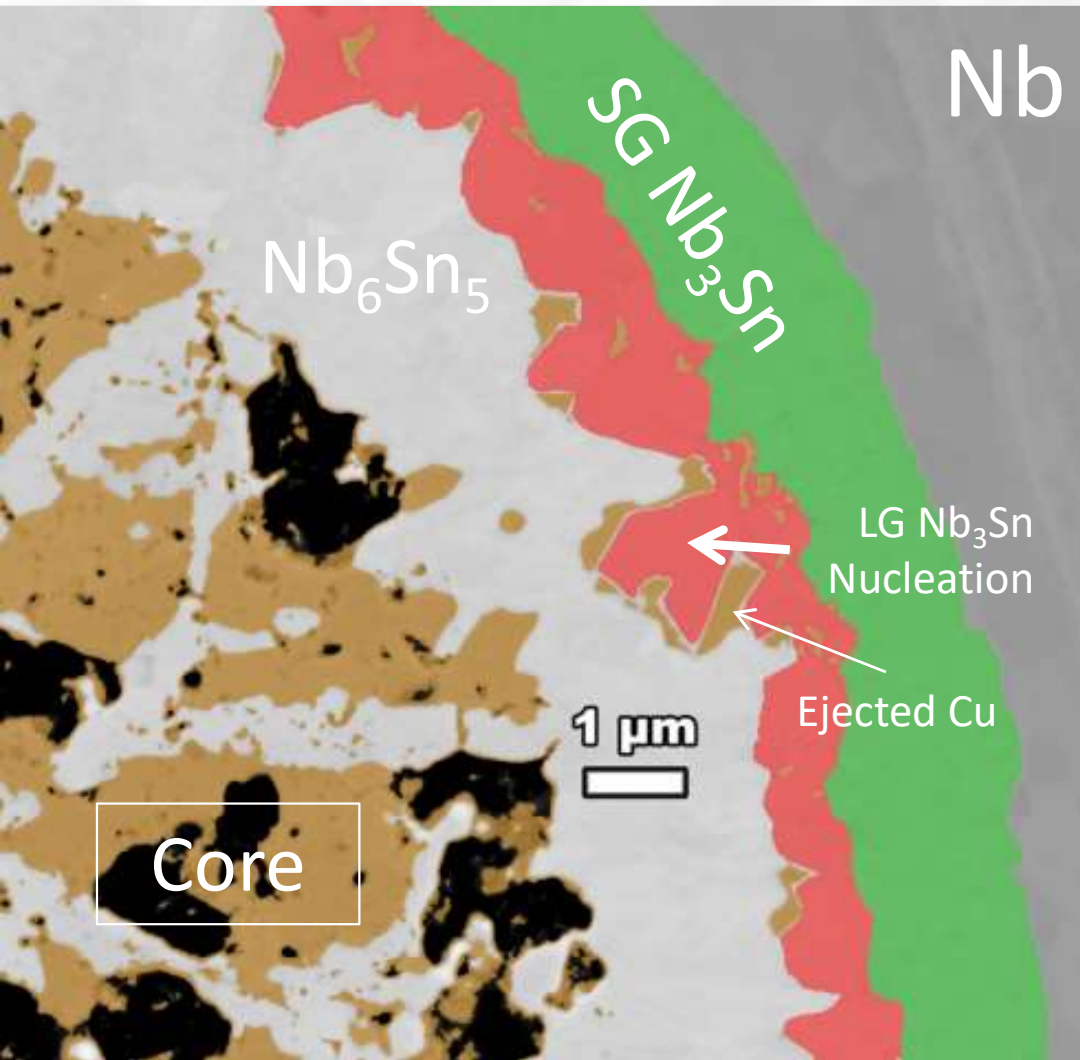
630°C - 12hr



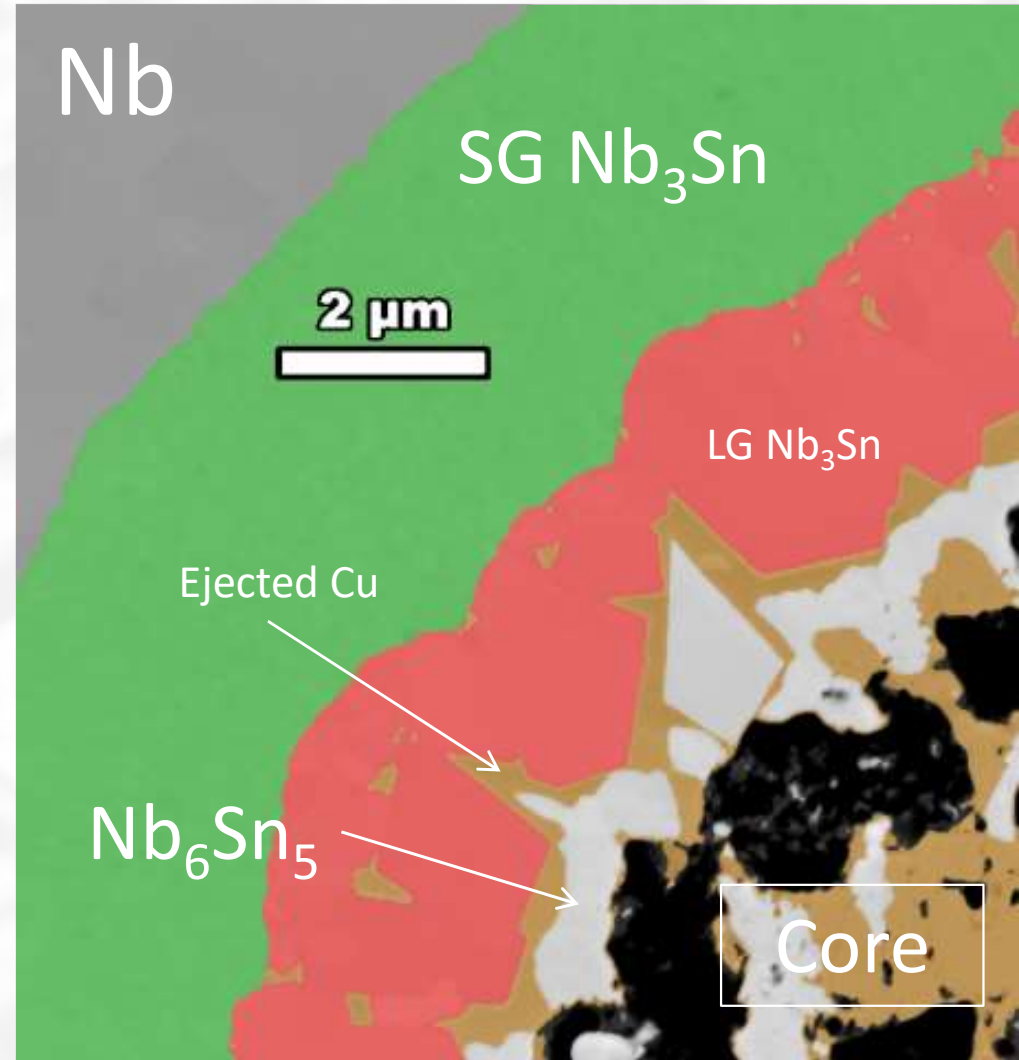
- What role does Cu play in the reaction?

# LG A15 grows with time, a Cu-rich phase separates the A15 layer from the core

630°C - 30hr



630°C - 58hr



- Large grains of A15 are a continuous layer.
- All of the large grains are surrounded by a Cu rich phase

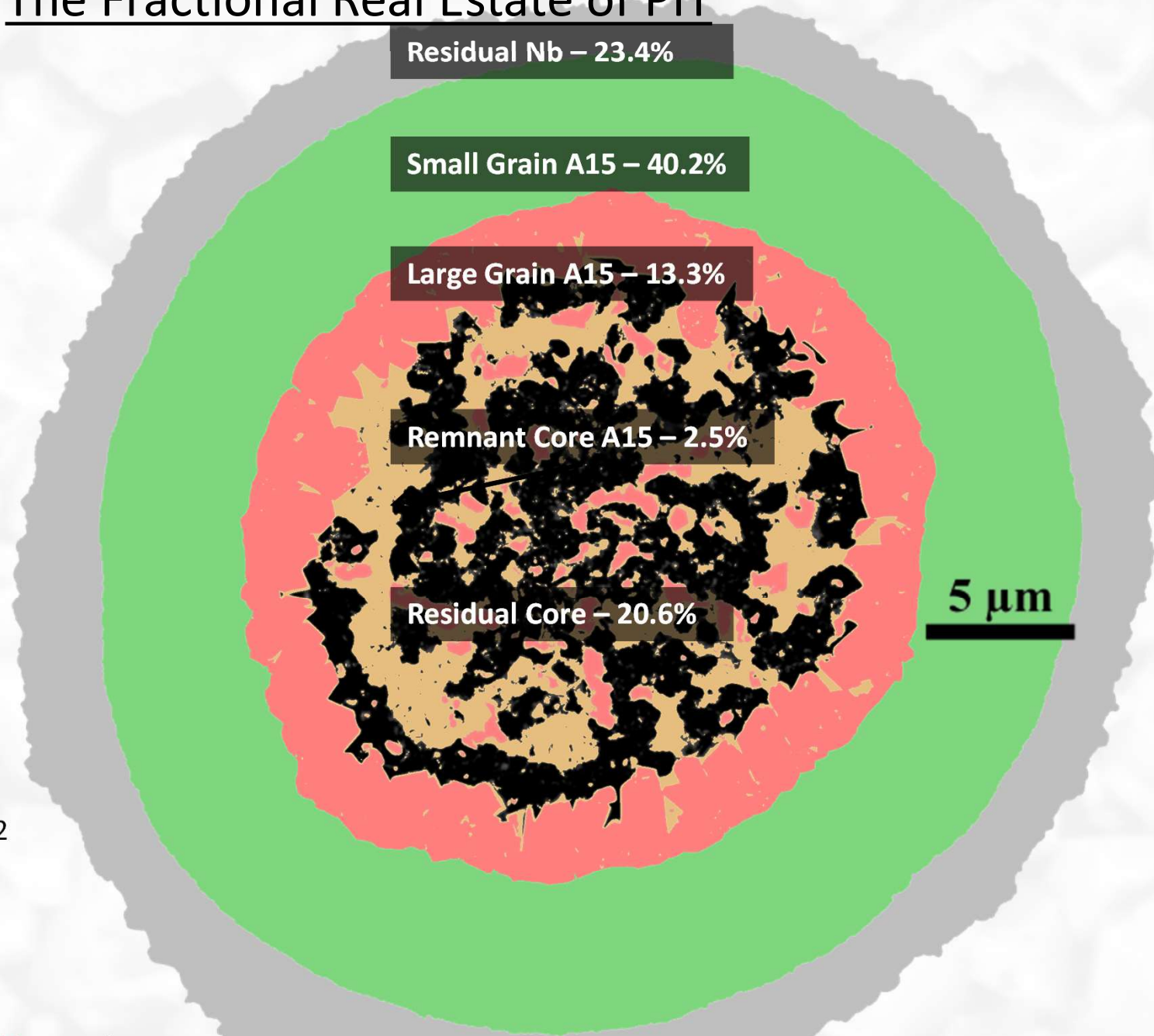
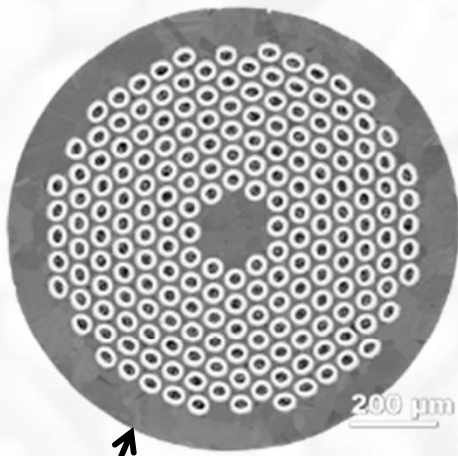
- There is a continuous layer of large grain A15 and penetrating Cu. A small amount of Nb<sub>6</sub>Sn<sub>5</sub> remains



# The Fractional Real Estate of PIT

- Wire diameter: 0.78mm
- Filament diameter: 39  $\mu\text{m}$

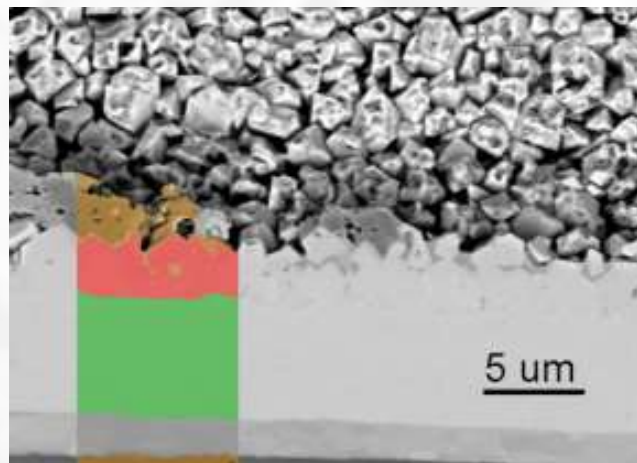
- Optimal HT from BEAS:  
620/100 + 640/120



- $I_c = 501 \text{ A}$
- $J_{c \text{ non-Cu}} = 2237 \text{ A/mm}^2$
- $J_{c \text{ layer}} = 5564 \text{ A/mm}^2$

- Only **small grain A15** carries current
- **Large and core grains of A15** do not carry any current.

Can we convert the poorly connected **large grains** and **core grains of A15** into **current carrying small grain A15** phase by only altering the heat treatment?





# LG A15 formation is temperature dependent

Only **SG A15** has formed

**LG A15** has nucleated with **Cu**

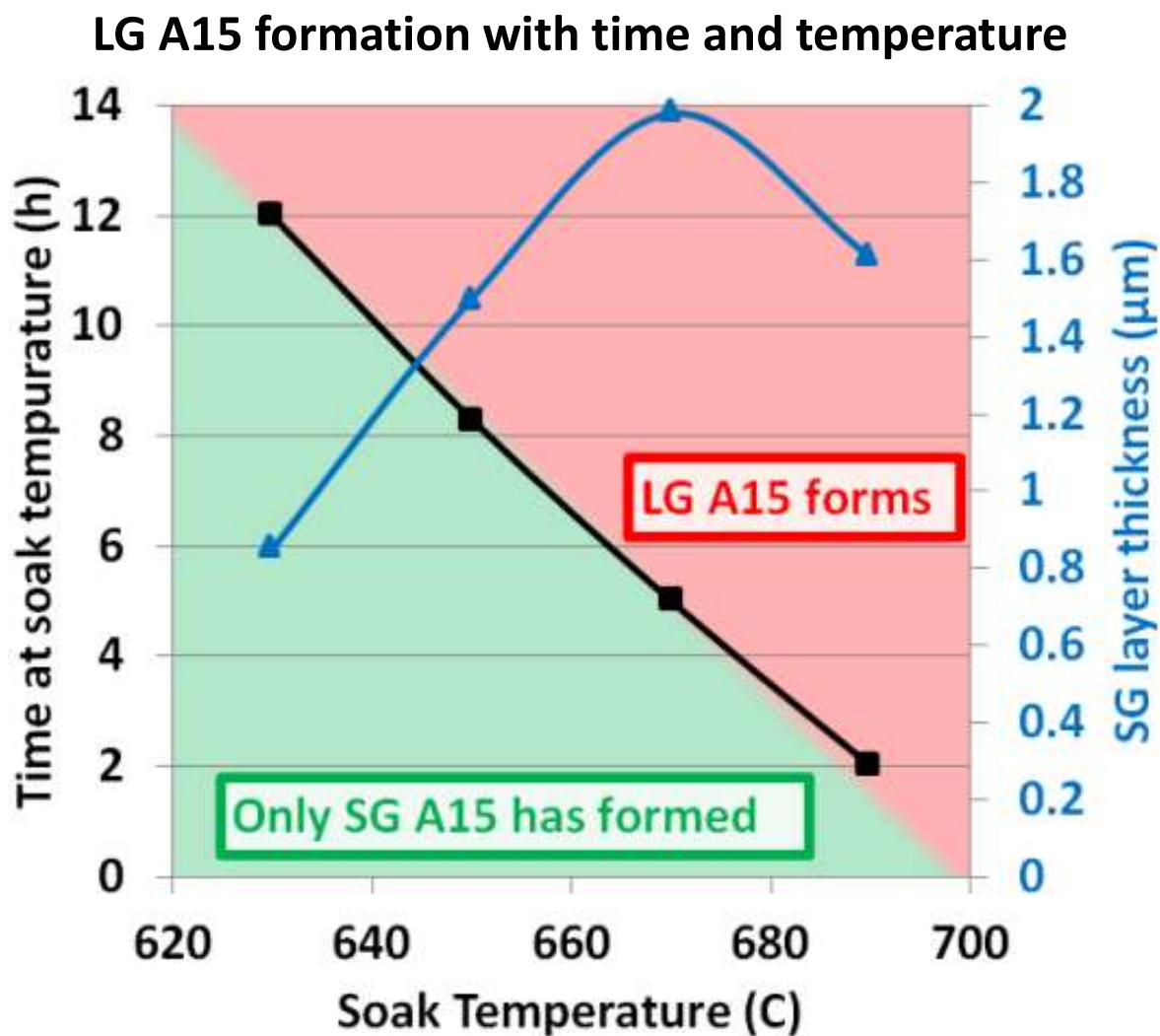
Increasing Temperature

630C 10h

650C 4.75h

670C 4.5h

690C 1.66h



630C 12h

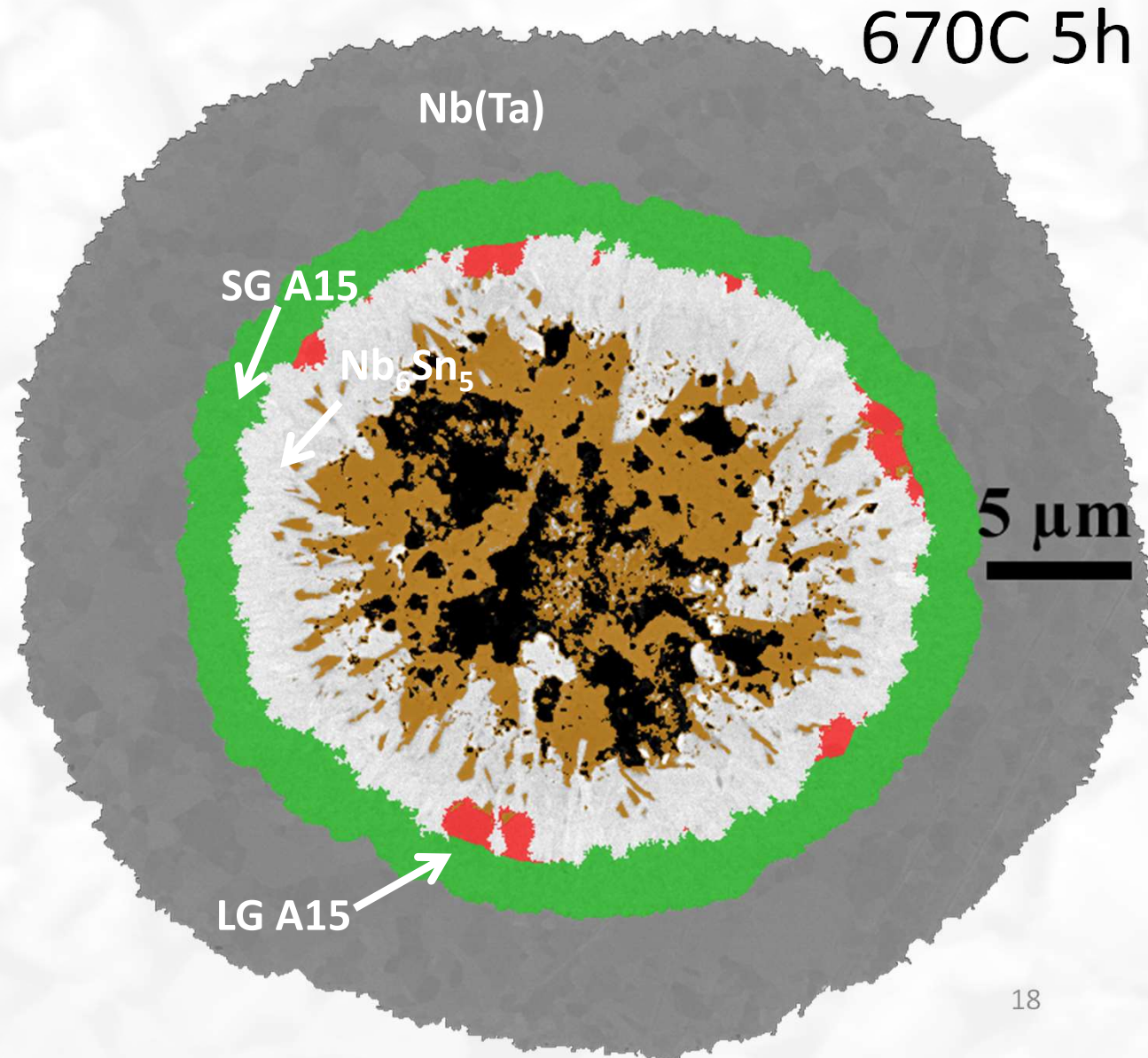
650C 8.33h

670C 5h

670C 2h

SG A15 forms *\*first\** by  $\text{Nb}_6\text{Sn}_5$  reacting with the tube.  
LG A15 forms by decomposition of  $\text{Nb}_6\text{Sn}_5$ .

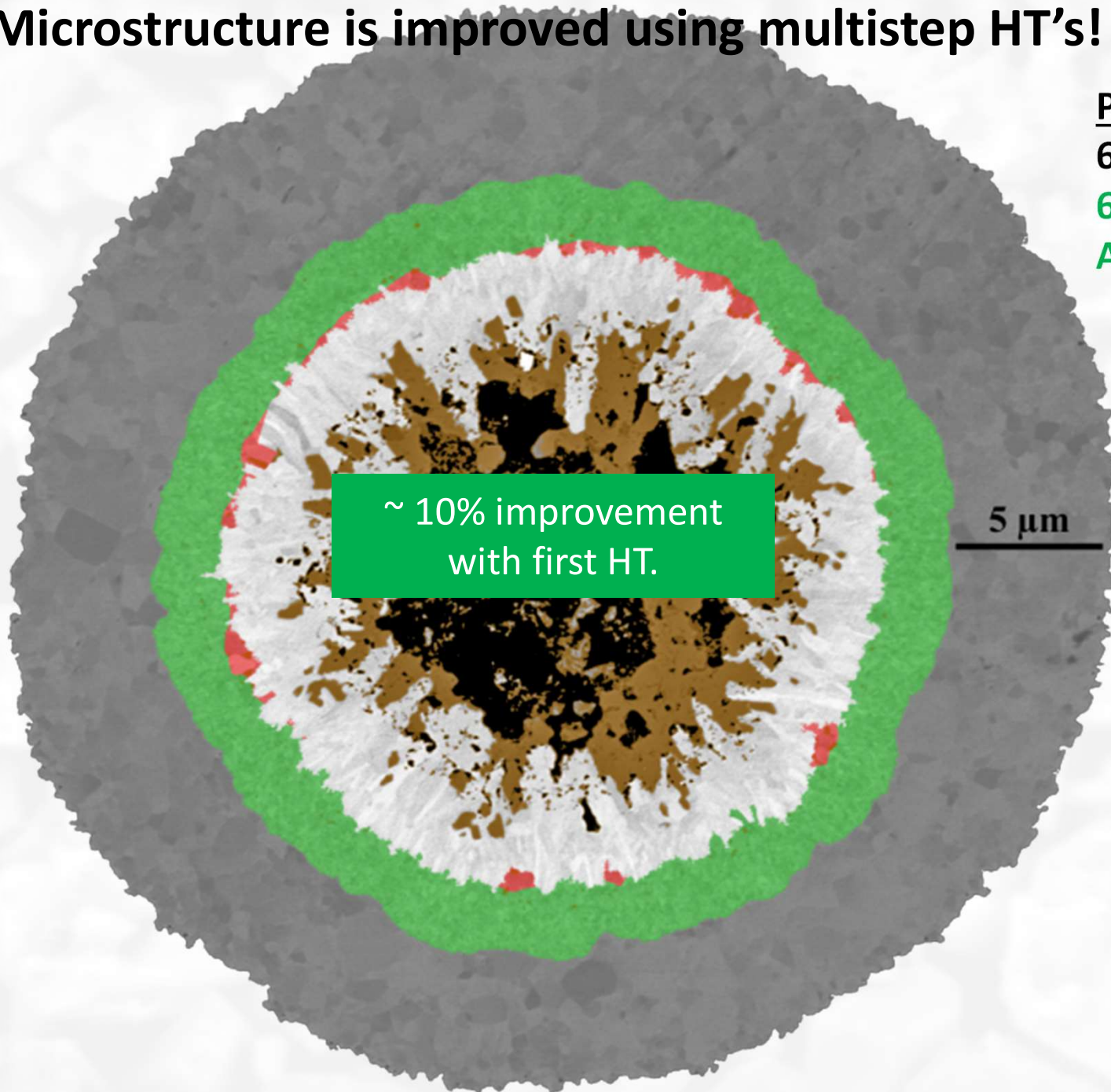
- After 5 hours at  $670^\circ\text{C}$ , there is nearly a  $2\ \mu\text{m}$  thick layer of SG A15 as the LG forms
- We do not believe that LG A15 forms directly from the tube material





Can a multistep heat treatment  
suppress **LG formation**?

## Microstructure is improved using multistep HT's!



### Previous HT's

630/12      0.8  $\mu\text{m}$

670/5        2.0  $\mu\text{m}$

A+630/13    2.2  $\mu\text{m}$

\*Steps are at higher temperatures

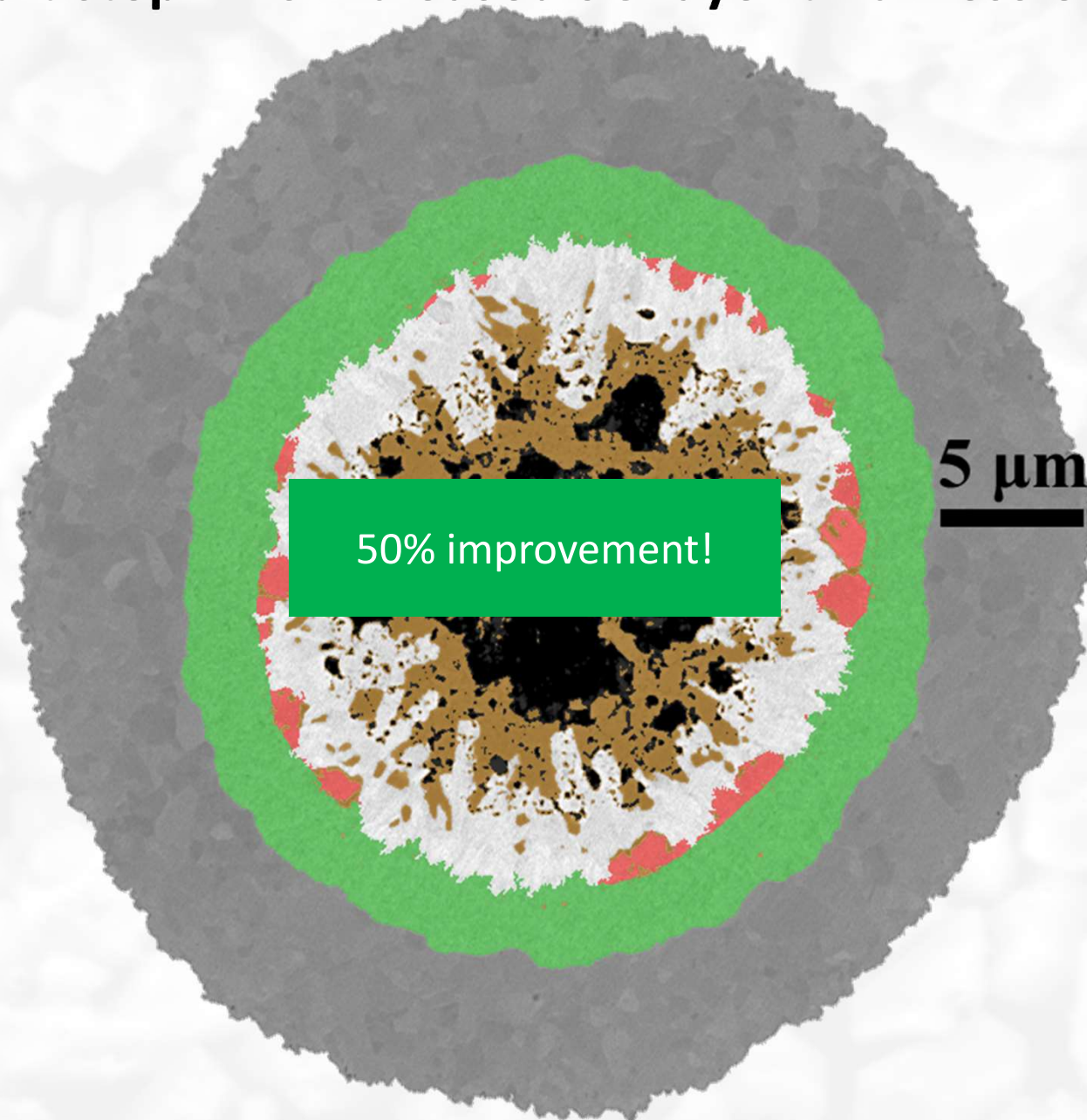
~ 10% improvement  
with first HT.

5  $\mu\text{m}$

**Step A + 630 °C 13h – 2.2  $\mu\text{m}$  SG layer thickness!**



# Refining multistep HT's increased SG layer thickness early in reaction



## Previous HT's

630/12 0.8 μm

670/5 2.0 μm

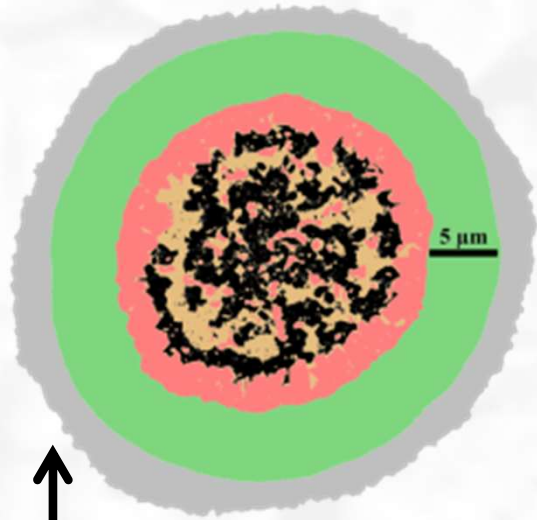
A+630/13 2.2 μm

C+630/10 3.0 μm

\*Steps are at higher temperatures

**Step C + 630 °C 10h – 3.0 μm SG layer thickness!**

# Multistep Heat Treatments do well converting core and LG A15 to more SG A15



- Sample B31284, 0.78mm wire
- Heat treatments done at ASC
- Critical current measurements on short samples (~ 4cm) at 12T, 4.2K

Heat treatment description	Heat treatment (temp/soak time)	$I_c$ (A)	$J_c$ (A/mm <sup>2</sup> )	$J_c$ SG-layer (A/mm <sup>2</sup> )	Nb	Total A15	core A15	LG A15	SG A15
BEAS recommended	620/100+640/120	501	2237	5564	23.4%	56.0%	2.5%	13.3%	40.2%

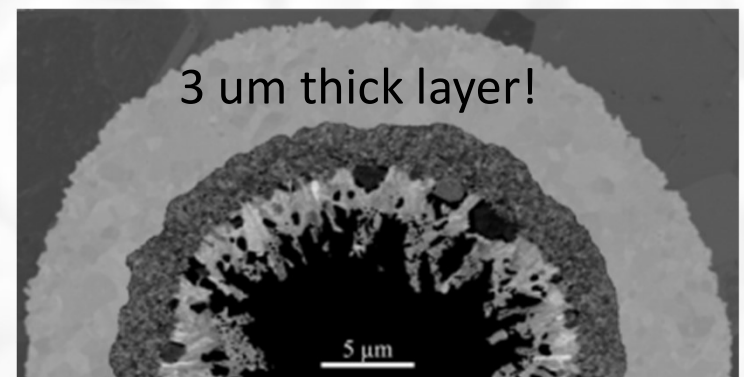
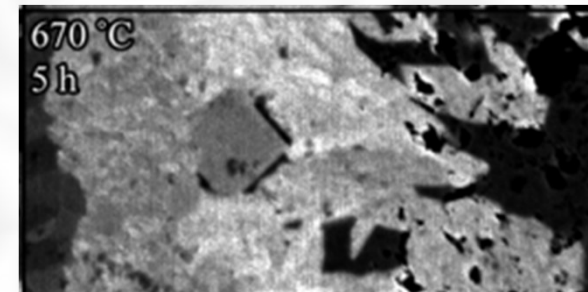
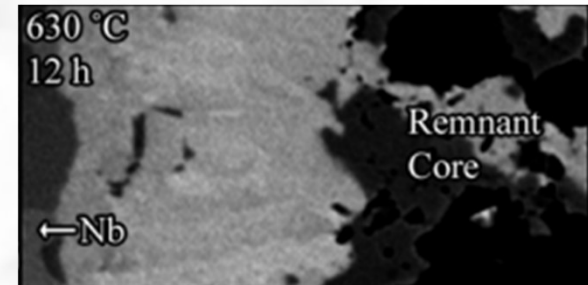
## Why?

- The steps before soaking at 630°C are higher temperature— producing larger grains of SG A15 than BEAS recommended HT



# Summary of LG formation experiments

- Initial low temp HT at 630°C creates a thin layer of **SG A15** before **LG's** nucleate from the  $\text{Nb}_6\text{Sn}_5$ .  
(0.85  $\mu\text{m}$ )
- At higher temperatures (670°C), this **SG layer is 2x** it's low temp counterpart.  
(1.98  $\mu\text{m}$ )
- Using multistep HT (630°C- 690°C), we can get **3x the layer thickness** without **LG** forming  
(3.0  $\mu\text{m}$ )



# Findings for discussion

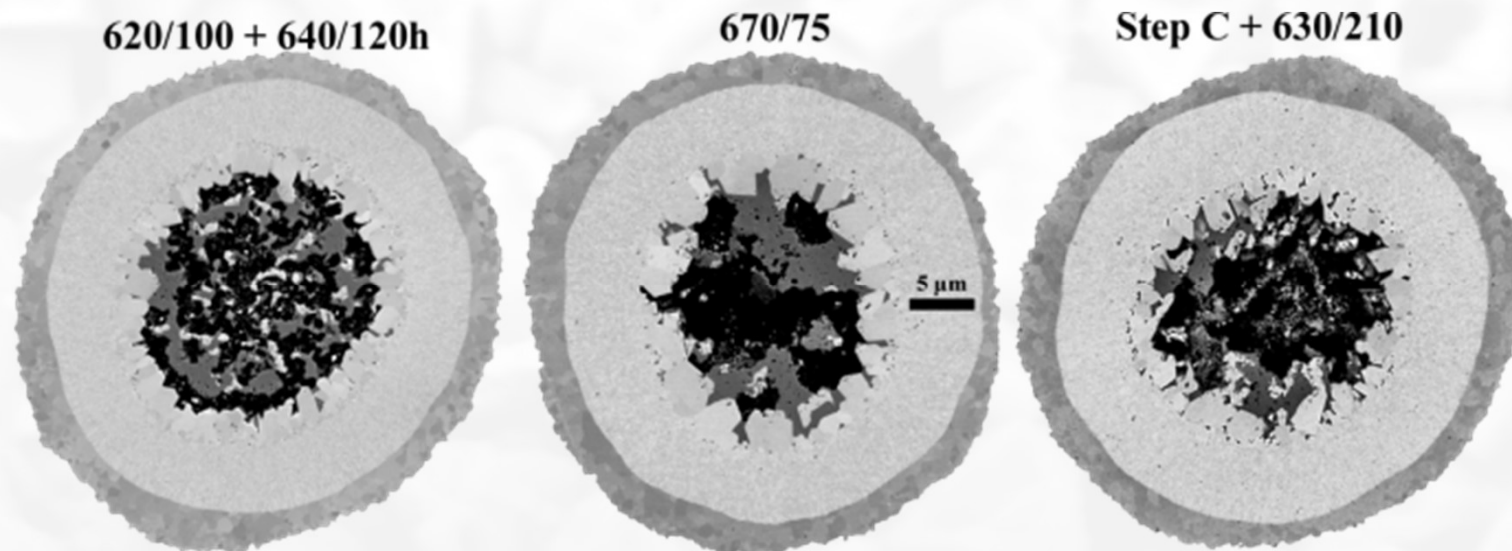
## The two main A15 morphologies form by different reaction paths

- Small grains of A15 form by  $\text{Nb}_6\text{Sn}_5$  feeding Sn into the Nb(Ta) diffusion barrier.
  - SG A15 ALWAYS forms first.
- Large grains of A15 form mostly by decomposition of  $\text{Nb}_6\text{Sn}_5$  in the core after some critical exhaustion point in the reaction.

## More SG A15 forms with higher temperature reactions

- High temperature reactions tend to reduce core grains by allowing more of the Sn source in the core to react with the Nb-7.5wt.%Ta tube
  - Quench experiments show this happens in the early hours of the reaction
    - A short, high temperature spike early on gives the same effect even when soaking at low temperature for most of the reaction

We believe under these novel multistep heat treatments, the filaments can utilize more Sn efficiently, and by changing the ratio of Nb/Sn/Cu in the core, it may be possible to prevent the core Nb from nucleating large grains of A15 and drive up  $J_c$ .





# Acknowledgements

David Larbalestier  
 Peter Lee  
 Chiara Tarantini

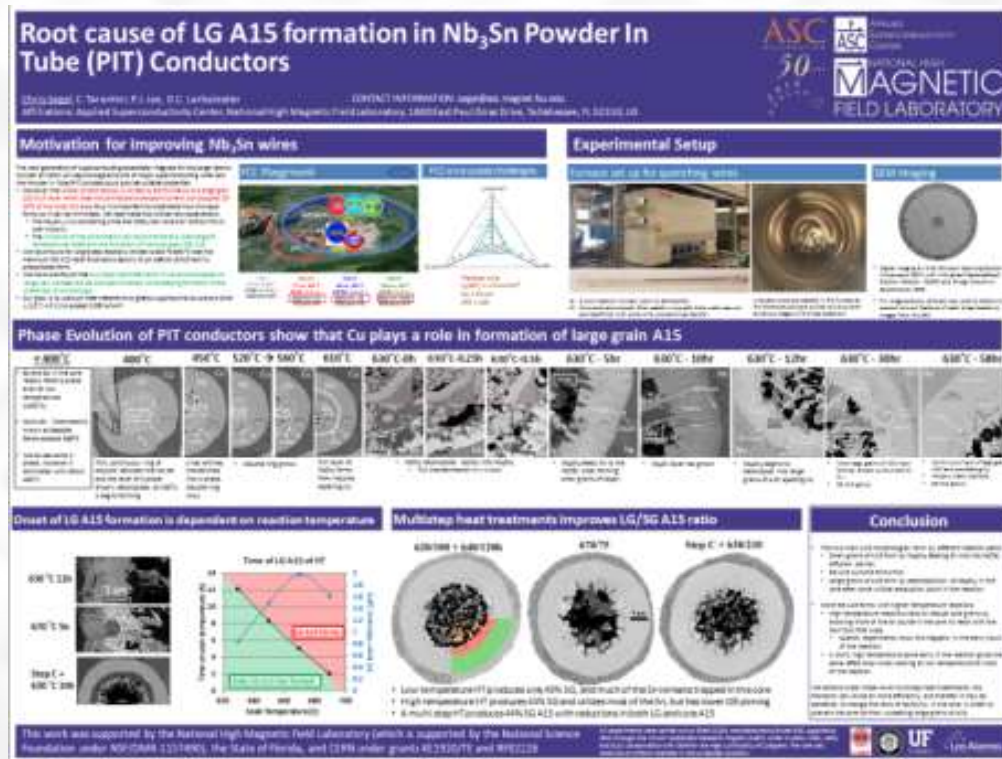


2MPo1C-07[166]

Amalia Ballarino  
 Luca Bottura  
 Christian Scheuerlein  
 Bernardo Bordini



Klaus Schlenga  
 Bernd Sailer  
 Manfred Thoener



# End of Presentation



**675 °C reacted for 4 hours**  
**– a much thicker SG layer has formed**

This SG A15 layer looks much thicker than mine at 630 °C 12 hours...does the LG A15 form differently as a function of reaction temperature?

**large grain has formed**

